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# **2SA872, 2SA872A**

Silicon PNP Epitaxial

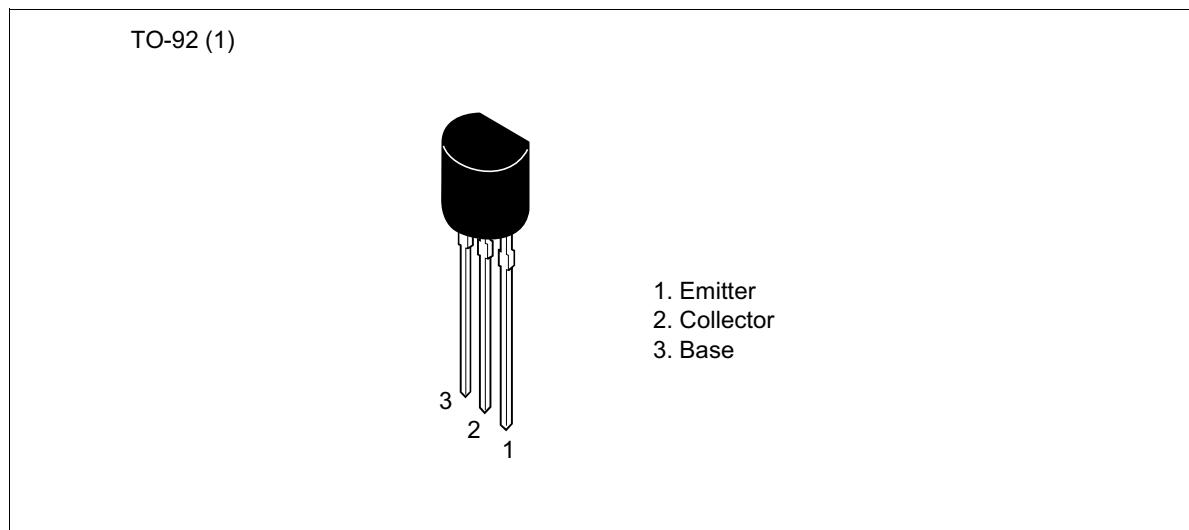
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## **Application**

- Low frequency low noise amplifier
- Complementary pair with 2SC1775/A

## **Outline**



## 2SA872, 2SA872A

### Absolute Maximum Ratings (Ta = 25°C)

| Item                         | Symbol           | 2SA872      | 2SA872A     | Unit |
|------------------------------|------------------|-------------|-------------|------|
| Collector to base voltage    | V <sub>CBO</sub> | -90         | -120        | V    |
| Collector to emitter voltage | V <sub>CEO</sub> | -90         | -120        | V    |
| Emitter to base voltage      | V <sub>EBO</sub> | -5          | -5          | V    |
| Collector current            | I <sub>C</sub>   | -50         | -50         | mA   |
| Collector power dissipation  | P <sub>C</sub>   | 300         | 300         | mW   |
| Junction temperature         | T <sub>j</sub>   | 150         | 150         | °C   |
| Storage temperature          | T <sub>stg</sub> | -55 to +150 | -50 to +150 | °C   |

### Electrical Characteristics (Ta = 25°C)

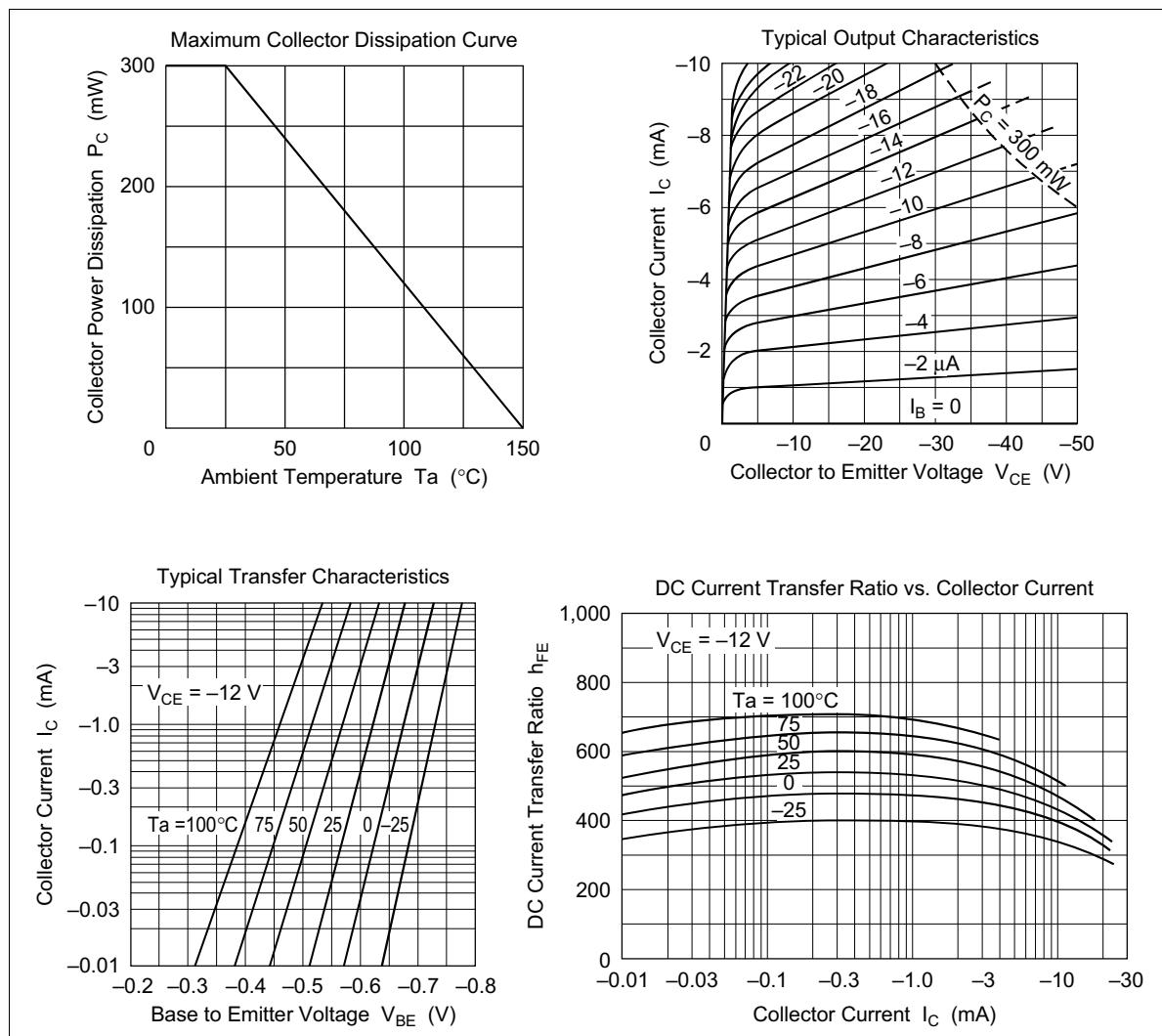
| Item  | Symbol               | 2SA872 |     |       | 2SA872A |     |       | Unit   | Test conditions  |
|---|----------------------|--------|-----|-------|---------|-----|-------|--|--|
|   |                      | Min    | Typ | Max   | Min     | Typ | Max   |  |  |
| Collector to emitter breakdown voltage                    | V <sub>(BR)CEO</sub> | -90    | —   | —     | -120    | —   | —     | V  | I <sub>C</sub> = -1 mA, R <sub>BE</sub> = ∞  |
| Collector cutoff current                                  | I <sub>CBO</sub>     | —      | —   | -0.5  | —       | —   | —     | μA   | V <sub>CB</sub> = -75 V, I <sub>E</sub> = 0  |
|   |                      | —      | —   | —     | —       | —   | -0.5  | μA   | V <sub>CE</sub> = -100 V, I <sub>E</sub> = 0   |
| DC current transfer ratio h <sub>FE1</sub> * <sup>1</sup> | h <sub>FE1</sub>     | 250    | —   | 800   | 250     | —   | 800   | V <sub>CE</sub> = -12 V,<br>I <sub>C</sub> = -2 mA   |  |
|   | h <sub>FE2</sub>     | 160    | —   | —     | 160     | —   | —     | V <sub>CE</sub> = -12 V,<br>I <sub>C</sub> = -0.1 mA |  |
| Base to emitter voltage                                   | V <sub>BE</sub>      | —      | —   | -0.75 | —       | —   | -0.75 | V  | V <sub>CE</sub> = -12 V,<br>I <sub>C</sub> = -2 mA                                     |
| Collector to emitter saturation voltage                   | V <sub>CE(sat)</sub> | —      | —   | -0.5  | —       | —   | -0.5  | V  | I <sub>C</sub> = -10 mA,<br>I <sub>B</sub> = -1 mA                                     |
| Gain bandwidth product f <sub>T</sub>                     | f <sub>T</sub>       | —      | 120 | —     | —       | 120 | —     | MHz  | V <sub>CE</sub> = -12 V,<br>I <sub>C</sub> = -2 mA                                     |
| Collector output capacitance                              | C <sub>ob</sub>      | —      | 1.8 | —     | —       | 1.8 | —     | pF   | V <sub>CB</sub> = -25 V, I <sub>E</sub> = 0,<br>f = 1 MHz                              |
| Noise figure  | NF                   | —      | —   | 5.0   | —       | —   | 5.0   | dB   | V <sub>CE</sub> = -6 V, f = 10 Hz<br>I <sub>C</sub> = -50 μA<br>R <sub>g</sub> = 50 kΩ |
|   |                      | —      | —   | 1.5   | —       | —   | 1.5   | dB   | f = 1 kHz  |

Note: 1. The 2SA872/A is grouped by h<sub>FE1</sub> as follows.

| D          | E          |
|------------|------------|
| 250 to 500 | 400 to 800 |

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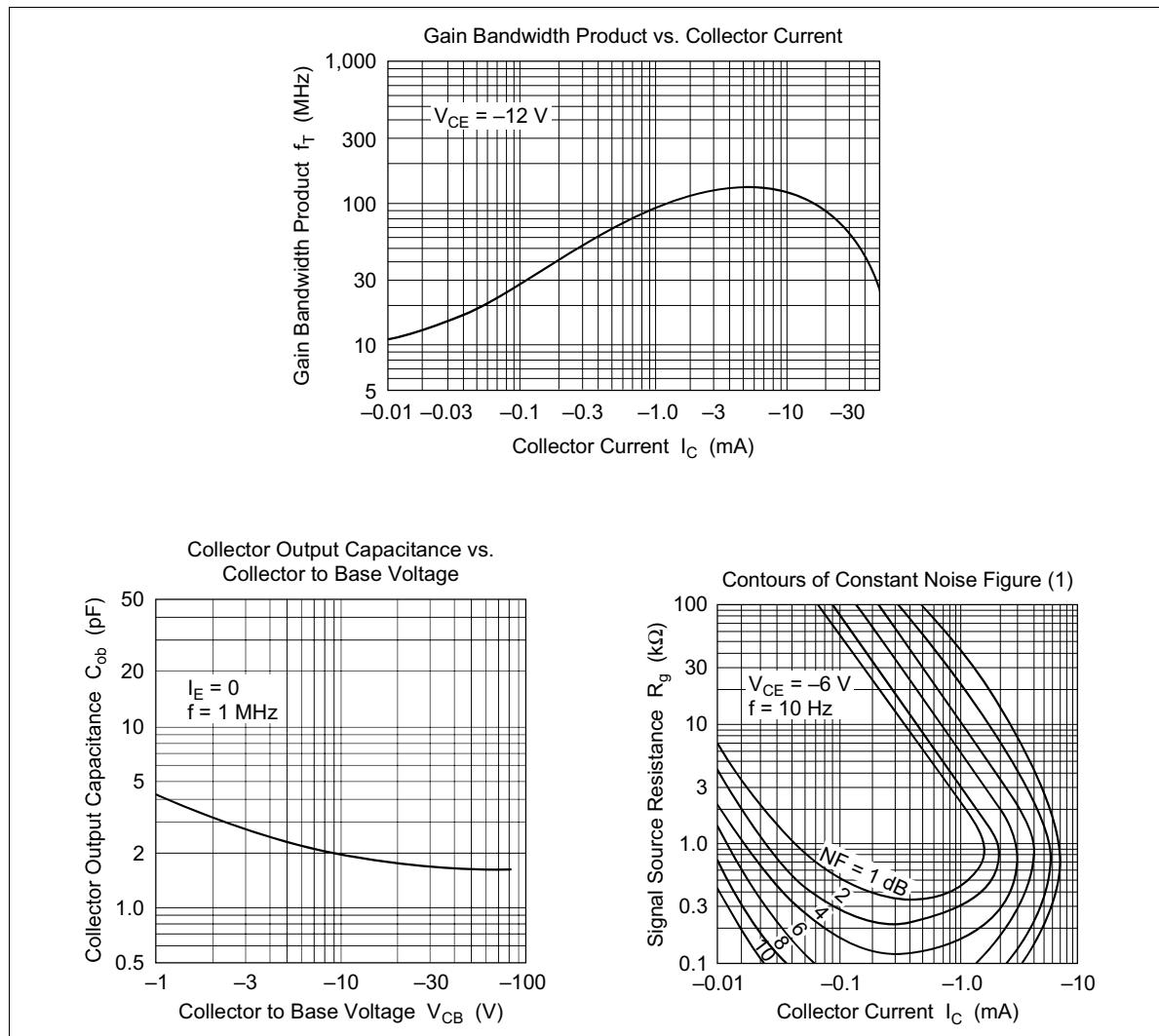


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## 2SA872, 2SA872A

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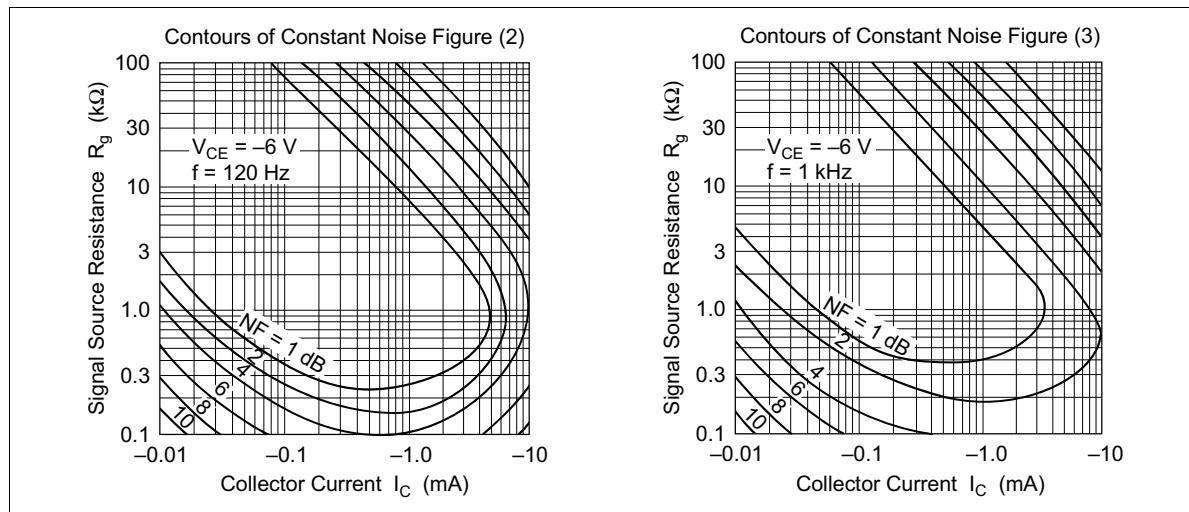
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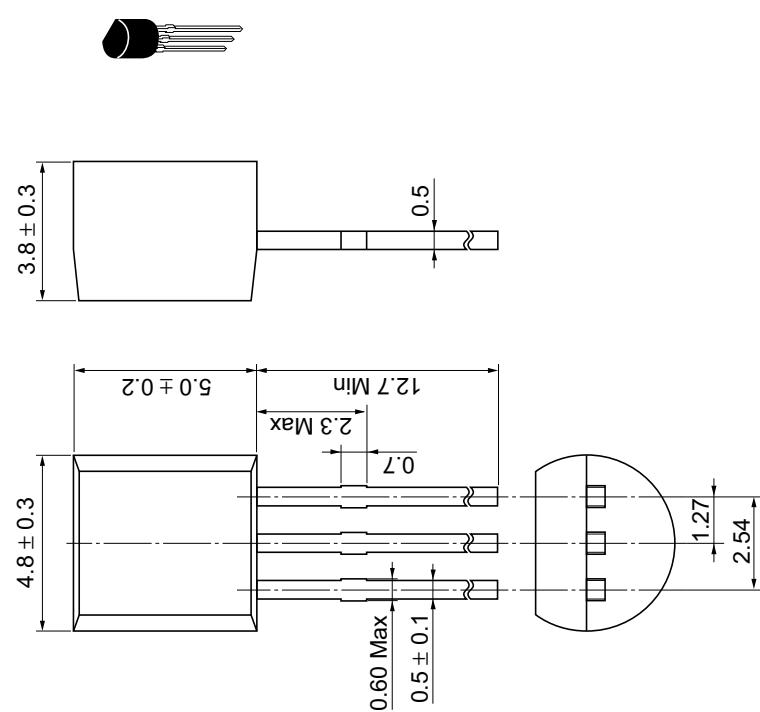
## 2SA872, 2SA872A

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Unit: mm



|                          |           |
|--------------------------|-----------|
| Hitachi Code             | TO-92 (1) |
| JEDEC                    | Conforms  |
| EIAJ                     | Conforms  |
| Weight (reference value) | 0.25 g    |

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